



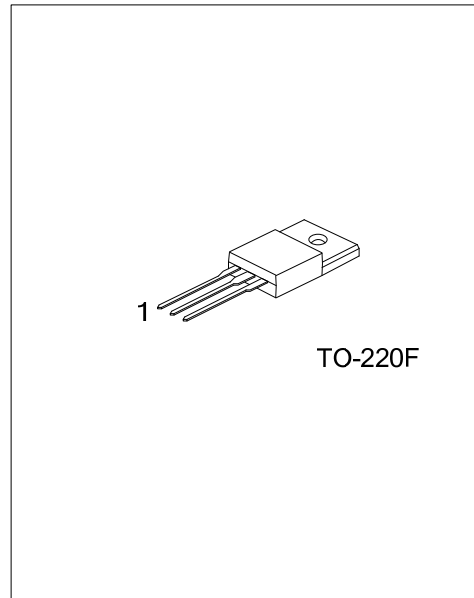
## 2SB1216

## NPN PLANAR TRANSISTOR

### HIGH CURRENT SWITCHING APPLICATIONS

#### FEATURES

- \* Low collector-to-emitter saturation voltage
- \* Good linearity of  $h_{FE}$
- \* Small and slim package facilitating compactness of sets.
- \* High  $f_T$
- \* Fast switching speed
- \* Complement the 2SD1816



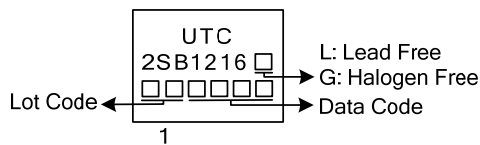
#### ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
2SB1216L-x-TF3-T	2SB1216G-x-TF3-T	TO-220F	B	C	E	Tube

Note: Pin assignment: B: Base C: Collector E: Emitter

<p>2SD1816L-x-TF3-T</p> <p>(1) Packing Type (2) Package Type (3) Rank (4) Green Package</p>	<p>(1) T: Tube, R: Tape Reel (2) TF3: TO-220F (3) x: refer to Classification of <math>h_{FE1}</math> (4) L: Lead Free, G: Halogen Free and Lead Free</p>
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#### MARKING



■ ABSOLUTE MAXIMUM RATINGS ( $T_A=25^{\circ}\text{C}$ , unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		$V_{CBO}$	-120	V
Collector-Emitter Voltage		$V_{CEO}$	-100	V
Emitter-Base Voltage		$V_{EBO}$	-6	V
Collector Current	DC	$I_C$	-4	A
	PULSE(Note 1)		-8	A
Collector Power Dissipation		$P_D$	2	W
Junction Temperature		$T_J$	+150	$^{\circ}\text{C}$
Storage Temperature		$T_{STG}$	-40 ~ +150	$^{\circ}\text{C}$

Note: 1. Duty=1/2, Pw=20ms

2. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

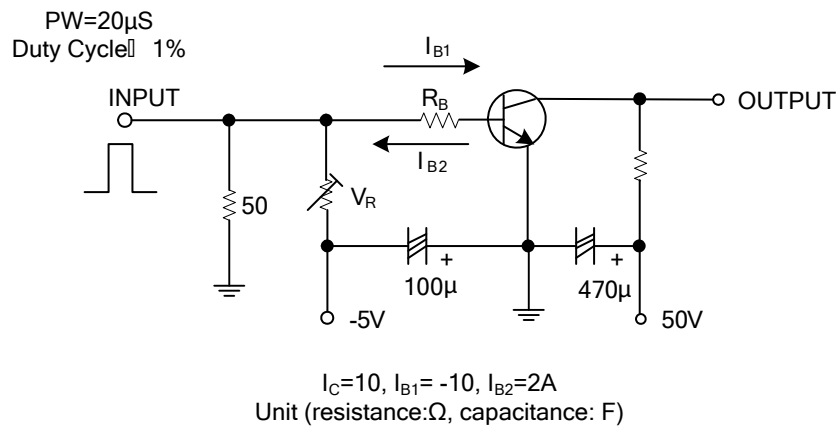
■ ELECTRICAL CHARACTERISTICS ( $T_A=25^{\circ}\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Base Breakdown Voltage	$BV_{CBO}$	$I_C = 10\mu\text{A}, I_E = 0$	-120			V
Collector Emitter Breakdown Voltage	$BV_{CEO}$	$I_C = 1\text{mA}, R_B = \infty$	-100			V
Emitter Base Breakdown Voltage	$BV_{EBO}$	$I_E = 10\mu\text{A}, I_C = 0$	-6			V
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	$I_C = 2\text{A}, I_B = 0.2\text{A}$		-0.9	-1.2	V
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C = 2\text{A}, I_B = 0.2\text{A}$		-200	-500	mV
Collector Cut-Off Current	$I_{CBO}$	$V_{CB} = 100\text{V}, I_E = 0$			-1	$\mu\text{A}$
Emitter Cut-Off Current	$I_{EBO}$	$V_{EB} = 4\text{V}, I_C = 0$			-1	$\mu\text{A}$
DC Current Transfer Ratio	$h_{FE1}$	$V_{CE} = 5\text{V}, I_C = 0.5\text{A}$	70		400	
	$h_{FE2}$	$V_{CE} = 5\text{V}, I_C = 3\text{A}$	40			
Transition Frequency	$f_T$	$V_{CE} = 10\text{V}, I_C = 0.5\text{A}$		130		MHz
Output Capacitance	$C_{ob}$	$V_{CB} = 10\text{V}, I_E = 0\text{A}, f = 1\text{MHz}$		65		pF
Turn-on Time	$t_{ON}$	See test circuit		100		ns
Storage Time	$t_{STG}$	See test circuit		800		ns
Fall Time	$t_F$	See test circuit		50		ns

■ CLASSIFICATION of  $h_{FE1}$

RANK	Q	R	S	T
RANGE	70 - 140	100 - 200	140 - 280	200 - 400

### ■ TEST CIRCUIT



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